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View Online at https://aerobasegroup.com/nsn/5961-00-050-3460
Inclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Terminal Length:
Between 1.500 inches and 1.750 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
120.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 100.0 collector to emitter
reverse voltage and 7.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
500.00 milliamperes source cutoff current
Power Rating Per Characteristic:
3.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-prf-19500/182 government specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

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Mil-std (military Standard):

Mil-prf-19500 spec.